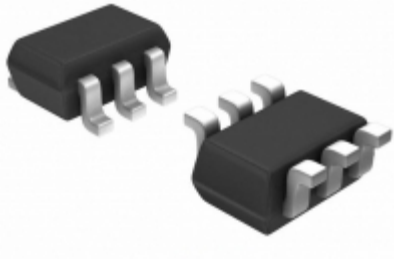

	<h2 style="color: red;">SI1905BDH-T1-E3</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: SI1905BDH-T1-E3
	Hersteller / Marke: Vishay / Siliconix
	Teil der Beschreibung: MOSFET 2P-CH 8V 0.63A SC70-6
	Datenblätter:  SI1905BDH-T1-E3.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 43170 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	SI1905BDH-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2P-CH 8V 0.63A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	43170 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	357mW
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6 (SOT-363)
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	8V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	630mA
Rds On (Max) @ Id, Vgs	542 mOhm @ 580mA, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	1.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	62pF @ 4V
Verpackung	Tape & Reel (TR)



















































SI1905BDH-T1-E3 ist neu im Original. Suche SI1905BDH-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1905BDH-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1905BDH-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1903DL-T1-GE3 Vishay / Siliconix MOSFET 2P-CH 20V 0.41A SC70-6</p>	 <p>SI1904EDH-T1-GE3 VISHAY SI1904EDH-T1-GE3 VISHAY</p>	 <p>SI1905DL VISHAY SI1905DL VISHAY</p>	 <p>SI1905BDH-T1-E3 VISHAY SI1905BDH-T1-E3 VISHAY</p>
 <p>SI1903DL-T1-E3 Vishay / Siliconix MOSFET 2P-CH 20V 0.41A SC70-6</p>	 <p>SI1905DL-T1 VISHAY SI1905DL-T1 VISHAY</p>	 <p>SI1905BDH-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 8V 0.63A SC70-6</p>	 <p>SI1904EDH-T1 SI SI1904EDH-T1 SI</p>

heiße Teile

Mehr

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|--|---|--|---|--|
|  SI1900DL-T1 |  SI1900DL-T1-E3 |  SI1900DL-T1-E3 |  SI1900DL-T1-GE3 |  SI1900DL-T1-GE3 |
|  SI1901DL-T1 |  SI1901DL-T1-E3 |  SI1902CDL-T1-GE3 |  SI1902CDL-T1-GE3 |  SI1902DL |
|  SI1902DL-T1 |  SI1902DL-T1-E1 |  SI1902DL-T1-E3 |  SI1902DL-T1-E3 |  SI1902DL-T1-GE3 |
|  SI1902DL-T1-GE3 |  SI1903DL |  SI1903DL-T1 |  SI1903DL-T1-E3 |  SI1903DL-T1-E3 |
|  SI1903DL-T1-GE3 |  SI1903DL-T1-GE3 |  SI1904EDH-T1 |  SI1904EDH-T1-GE3 |  SI1905BDH-T1-E3 |
|  SI1905BDH-T1-GE3 |  SI1905BDH-T1-E3 |  SI1905DL |  SI1905DL-T1 |  SI1905DL-T1-E3 |
|  SI1905DL-T1-E3 |  SI1905DL-T1-GE3 |  SI1906DL-T1 |  SI1912EDH |  SI1912EDH-T1 |
|  SI1912EDH-T1-E3 |  SI1912EDH-T1-E3 |  SI1912EDH-T1-GE3 |  SI1913DH-T1-E3 |  SI1913DH-T1-E3 |
|  SI1913DH-T1-GE3 |  SI1913EDH-T1 |  SI1913EDH-T1-E3 |  SI1913EDH-T1-E3 |  SI1913EDH-T1-GE3 |
|  SI1917EDH-T1 |  SI1917EDH-T1-E3 |  SI1917EDH-T1-E3 |  SI1917EDH-T1-GE3 |  SI1922EDH-T1-GE3 |

Contact us: Info@Y-IC.com

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